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June 2014

FDB024N08BL7

N-Channel PowerTrench® MOSFET

80 V, 229 A, 2.4 mΩ

Features

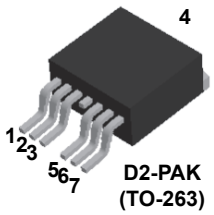
- $R_{DS(on)}$ = 1.7 mΩ (Typ.) @ V_{GS} = 10 V, I_D = 100 A
- Low FOM $R_{DS(on)}$ *Q_G
- Low Reverse Recovery Charge, Q_{rr} = 112 nC
- Soft Reverse Recovery Body Diode
- Enables Highly Efficiency in Synchronous Rectification
- Fast Switching Speed
- RoHS Compliant
- Qualified according to JEDEC Standards JESD22-A113F and IPC/JEDEC J-STD-020D.1

Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advance PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

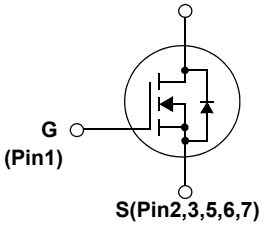
Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor drives and Uninterruptible Power Supplies



D2-PAK
(TO-263)

1. Gate
2. Source
3. Source
4. Drain
5. Source
6. Source
7. Source



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		FDB024N08BL7	Unit
V_{DSS}	Drain to Source Voltage		80	V
V_{GSS}	Gate to Source Voltage		±20	V
I_D	Drain Current	- Continuous (T_C = 25°C, Silicon Limited)	229*	A
		- Continuous (T_C = 100°C, Silicon Limited)	162*	
		- Continuous (T_C = 25°C, Package Limited)	120	
I_{DM}	Drain Current	- Pulsed (Note 1)	916	A
E_{AS}	Single Pulsed Avalanche Energy	(Note 2)	917	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	6.0	V/ns
P_D	Power Dissipation	(T_C = 25°C)	246	W
		- Derate Above 25°C	1.64	W/°C
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +175	°C
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C

*Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 120 A.

Thermal Characteristics

Symbol	Parameter	FDB024N08BL7	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.61	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	

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Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDB024N08BL7	FDB024N08B	D2PAK-7L	Tape and Reel	330 mm	24 mm	800 units

Electrical Characteristics $T_C = 25^oC$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV_{DSS}	Drain to Source Breakdown Voltage	I_D = 250 μA, V_{GS} = 0 V	80	-	-	V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C	-	0.05	-	V/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 64 V, V_{GS} = 0 V	-	-	1	μA
		V_{DS} = 64 V, T_C = 150°C	-	-	500	
I_{GSS}	Gate to Body Leakage Current	V_{GS} = ±20 V, V_{DS} = 0 V	-	-	±100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	V_{GS} = V_{DS}, I_D = 250 μA	2.5	-	4.5	V
$R_{DS(on)}$	Static Drain to Source On Resistance	V_{GS} = 10 V, I_D = 100 A	-	1.7	2.4	mΩ
g_{FS}	Forward Transconductance	V_{DS} = 10 V, I_D = 100 A	-	227	-	S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 40 V, V_{GS} = 0 V, f = 1 MHz	-	10170	13530	pF
C_{oss}	Output Capacitance		-	1670	2220	pF
C_{rss}	Reverse Transfer Capacitance		-	35	-	pF
C_{oss}(er)	Engry Related Output Capacitance	V_{DS} = 40 V, V_{GS} = 0 V	-	3025	-	pF
$Q_{g(tot)}$	Total Gate Charge at 10V	V_{DS} = 40 V, V_{GS} = 10 V, I_D = 100 A	-	137	178	nC
Q_{gs}	Gate to Source Gate Charge		-	56	-	nC
Q_{gs2}	Gate Charge Threshold to Plateau		-	25	-	nC
Q_{gd}	Gate to Drain “Miller” Charge	(Note 4)	-	28	-	nC
ESR	Equivalent Series Resistance (G-S)	f = 1MHz	-	2.4	-	Ω
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 40 V, I_D = 100 A, V_{GS} = 10 V, R_G = 4.7 Ω	-	47	104	ns
t_r	Turn-On Rise Time		-	66	142	ns
$t_{d(off)}$	Turn-Off Delay Time		-	87	184	ns
t_f	Turn-Off Fall Time	(Note 4)	-	41	92	ns
Drain-Source Diode Characteristics						
I_S	Maximum Continuous Drain to Source Diode Forward Current		-	-	229*	A
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	916	A
V_{SD}	Drain to Source Diode Forward Voltage	V_{GS} = 0 V, I_{SD} = 100 A	-	-	1.3	V
t_{rr}	Reverse Recovery Time	V_{GS} = 0 V, V_{DD} = 40 V, I_{SD} = 100 A, dI_F/dt = 100 A/μs	-	80	-	ns
Q_{rr}	Reverse Recovery Charge		-	112	-	nC

Notes:

1. Repetitive rating: pulse width limited by maximum junction temperature.
2. L = 3 mH, I_{AS} = 24.72 A, R_G = 25 Ω, starting T_J = 25°C.
3. I_{SD} ≤ 100 A, di/dt ≤ 200 A/μs, V_{DD} ≤ BV_{DSS}, starting T_J = 25°C.
4. Essentially independent of operating temperature typical characteristics.

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Typical Performance Characteristics

Figure 1. On-Region Characteristics

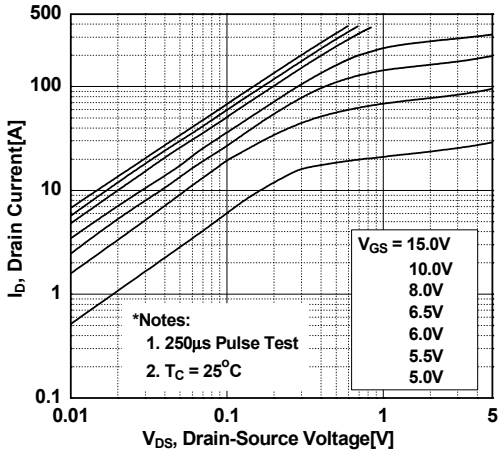


Figure 2. Transfer Characteristics

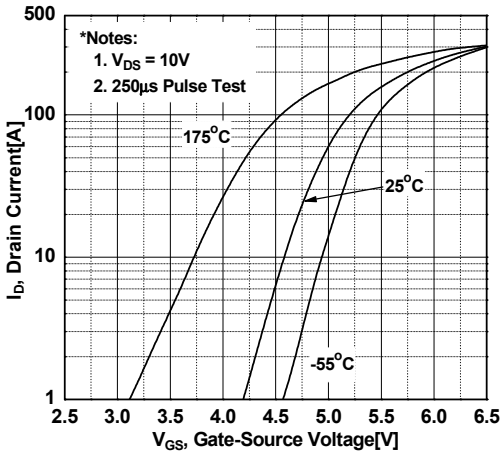


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

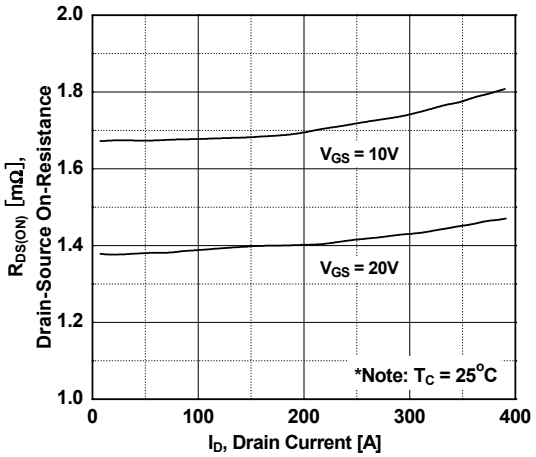


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

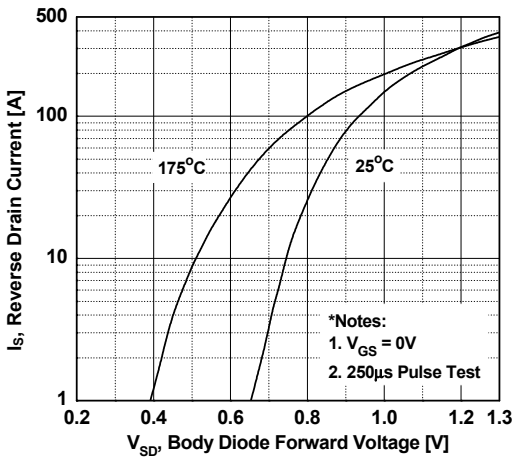


Figure 5. Capacitance Characteristics

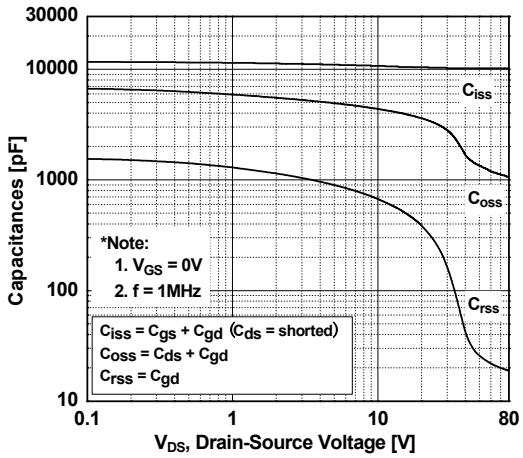
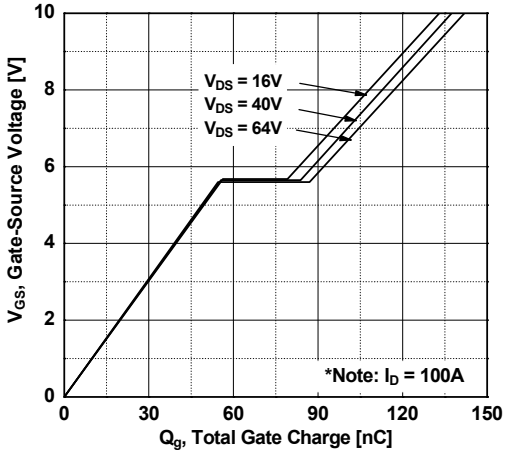


Figure 6. Gate Charge Characteristics



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Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

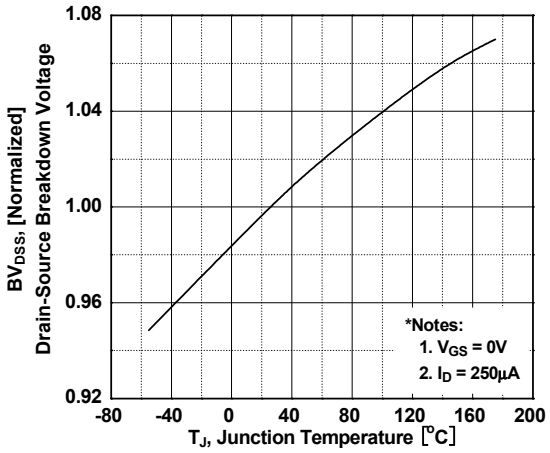


Figure 8. On-Resistance Variation vs. Temperature

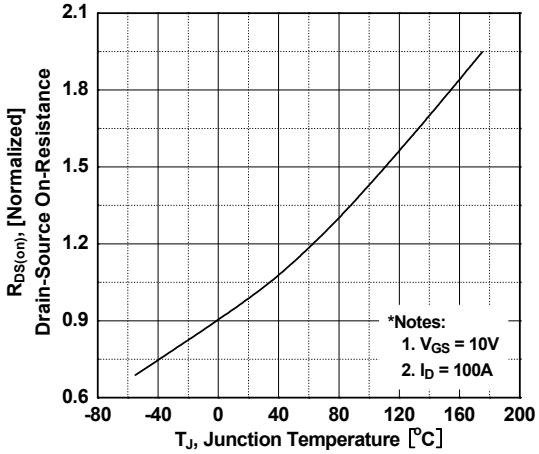


Figure 9. Maximum Safe Operating Area

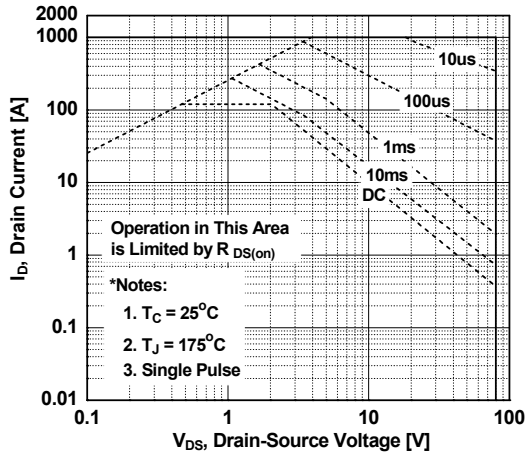


Figure 10. Maximum Drain Current vs. Case Temperature

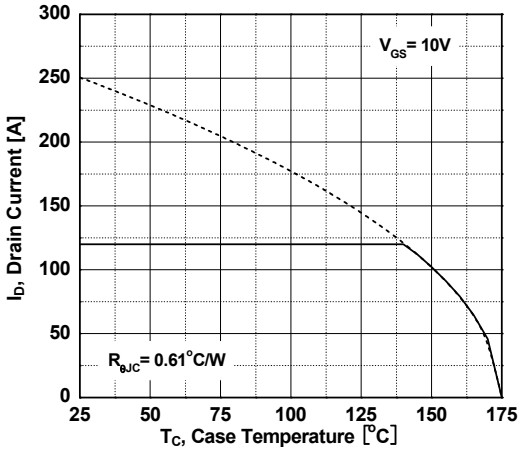


Figure 11. Eoss vs. Drain to Source Voltage

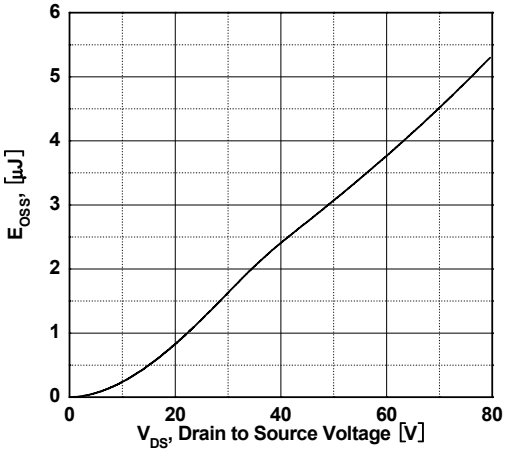
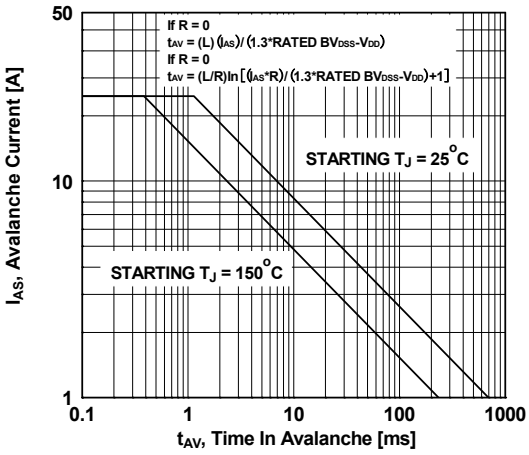


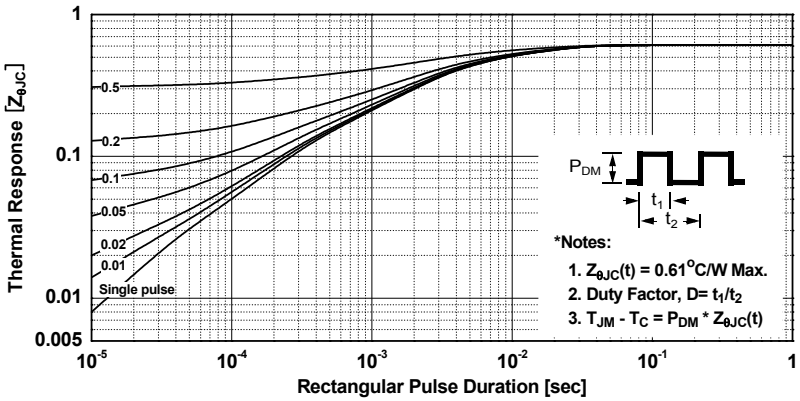
Figure 12. Unclamped Inductive Switching Capability



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Typical Performance Characteristics (Continued)

Figure 12. Transient Thermal Response Curve



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Figure 13. Gate Charge Test Circuit & Waveform

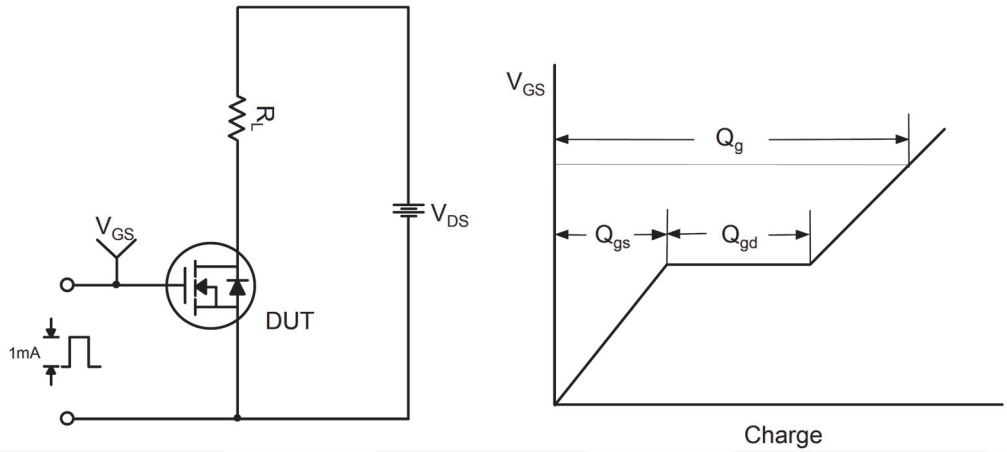


Figure 14. Resistive Switching Test Circuit & Waveforms

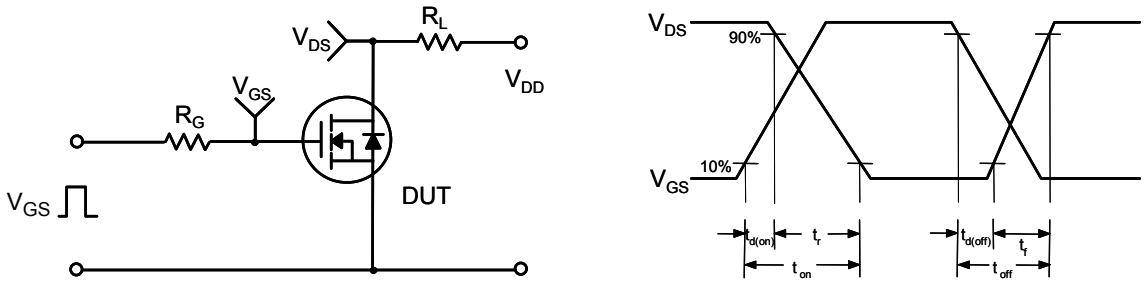
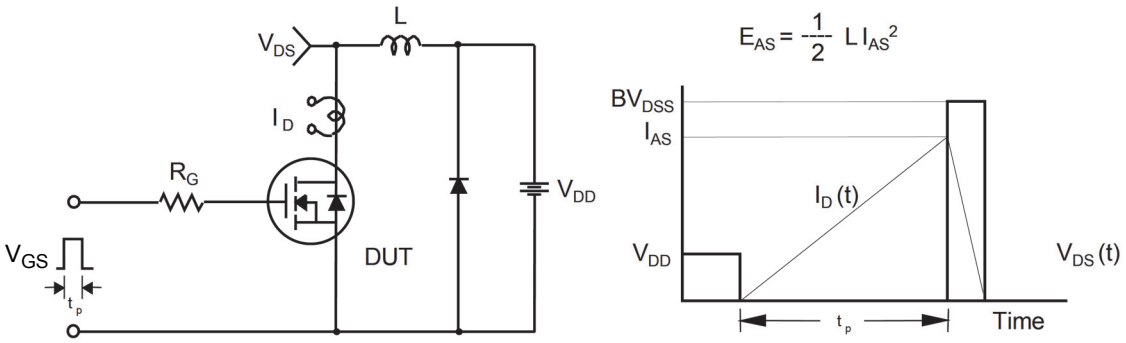
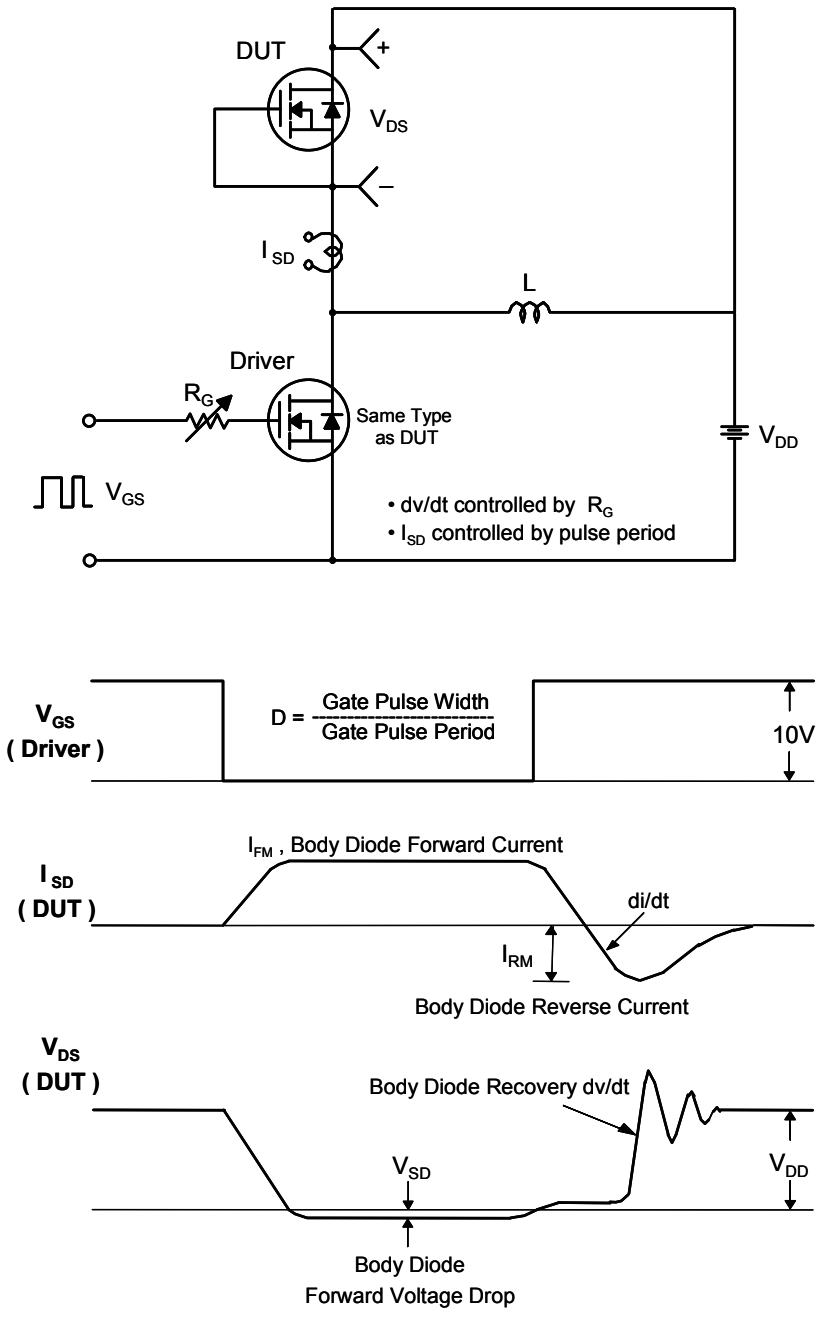


Figure 15. Unclamped Inductive Switching Test Circuit & Waveforms



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Figure 16. Peak Diode Recovery dv/dt Test Circuit & Waveforms



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Mechanical Dimensions

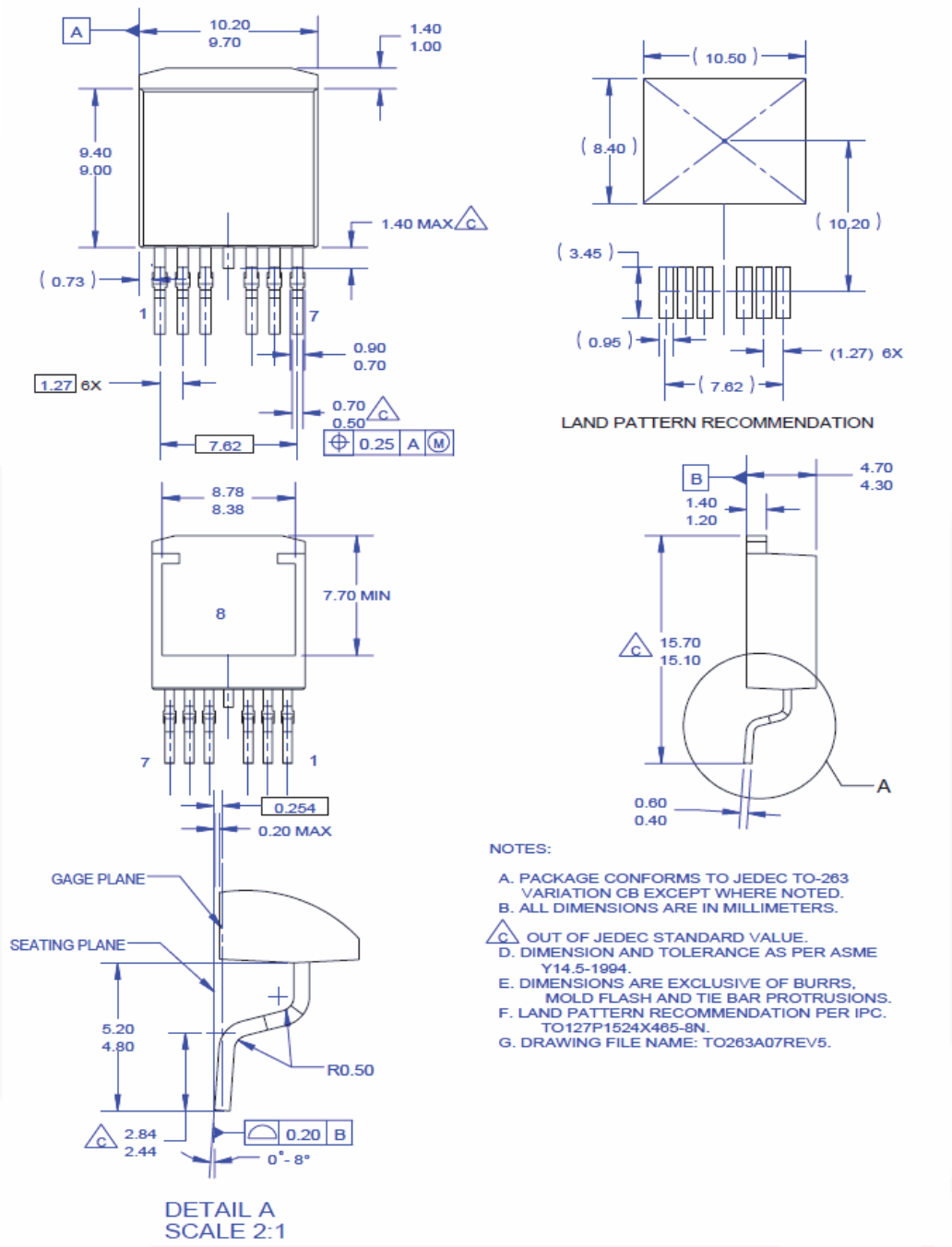


Figure 17. TO263 (D^2PAK), Molded, 7-Lead, Surface Mount

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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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